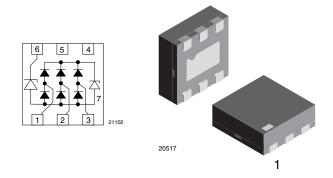
COMPLIANT

GREEN (5-2008)**



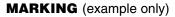
Vishay Semiconductors

USB-OTG BUS-Port ESD-Protection for V_{BUS} = 12 V



FEATURES

- Ultra compact LLP75-7L package
- Low package height < 0.6 mm
- 3-line USB ESD-protection with max. working range = 5.5 V
- V_{BUS} protection with 12 V working range
- · Low leakage current
- Low load capacitance C_D = 0.7 pF
- ESD-protection to IEC 61000-4-2
 ± 15 kV contact discharge
 - ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 I_{PP} > 3 A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC





Dot = Pin 1 marking XX = Date code

YY = Type code (see table below)

ORDERING INFORMATION						
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY			
VBUS053AZ-HAF	VBUS053AZ-HAF-GS08	15 000	15 000			

PACKAGE DATA								
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS		
VBUS053AZ-HAF	LLP75-7L	U9	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT			
Data line D+, D-, ID: Pin 1, 2 and 3 to ground (pin 7)							
Peak pulse current	acc. IEC 61000-4-5; t _p = 8/20 μs; single shot	I _{PPM}	3	Α			
Peak pulse power	acc. IEC 61000-4-5; t _p = 8/20 μs; single shot	P _{PP}	36	W			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV			
V _{BUS} : Pin 6 to ground (pin	7)						
Peak pulse current	acc. IEC 61000-4-5; tp = 8/20 μs/single shot	I _{PPM}	8	Α			
Peak pulse power	acc. IEC 61000-4-5; tp = 8/20 μs/single shot	P_{PP}	240	W			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV			
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C			
Storage temperature		T _{STG}	- 55 to + 150	°C			

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

VBUS053AZ-HAF



Vishay Semiconductors USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 12 \text{ V}$

ELECTRICAL CHARACTERISTICS All inputs (pin 1, 2, and 3) to ground (pin 7)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	3	lines	
Reverse working voltage	at I _R = 0.1 μA	V_{RWM}	5.5	-	-	V	
Reverse current	at V _R = V _{RWM} = 3.3 V; T = 65 °C	I _R	-	-	0.085	μΑ	
	at V _R = V _{RWM} = 5.5 V	I _R	-	-	1	μΑ	
Forward voltage	at I _F = 15 mA	V_{F}	0.7	-	1.2	V	
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6.5	-	10	V	
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	10	12	V	
	at I _{PP} = 3 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	15	18	V	
Forward clamping voltage	at I _F = 3 A; acc. IEC 61000-4-5	V_{F}	-	3.4	4.1	V	
Line capacitance	Test pin at $V_R = 0 \text{ V}$; any other I/O pin at $V_R = 3.3 \text{ V}$, $f = 1 \text{ MHz}$	C _D	-	0.7	1	pF	
Line symmetry	Difference of the line capacitance	dC_D	-	-	0.1	pF	
Line to line capacitance	Among pins 1, 2 and 3 at V _R = 0 V; f = 1 MHz	C _{DD}	-	0.35	0.5	pF	

Note

• Tamb = - 40 °C to 85 °C, unless otherwise specified

ELECTRICAL CHARACTERISTICS V _{BUS} (pin 6) to ground (pin 7)							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of line which can be protected	N _{channel}	-	-	1	line	
Reverse working voltage	at I _R = 100 nA	V_{RWM}	12	-	-	V	
Reverse current	at V _R = V _{RWM} = 12 V	I _R	-	-	100	nA	
Forward voltage	at I _F = 10 mA	V_{F}	0.6	0.75	0.9	V	
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	15	-	18	V	
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	17.5	20	V	
	at I _{PP} = 8 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	25	30	V	
Forward clamping voltage	at I _F = 8 A; acc. IEC 61000-4-5	V_{F}	-	-	2.2	V	
Line capacitance	at V _R = 0 V, f = 1 MHz	C _D	-	70	85	pF	

Note

• Tamb = - 40 $^{\circ}$ C to 85 $^{\circ}$ C, unless otherwise specified



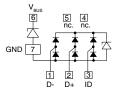
USB-OTG BUS-Port ESD-Protection Vishay Semiconductors for V_{BUS} = 12 V

APPLICATION NOTE

The VBUS053AZ-HAF is intended as an ESD-protection and transient voltage suppressor for one USB-OTG port.

The LLP75-7L package contains two separate dies which are mounted on a common ground plane (pin 7). The high-speed data lines D-, D+ and ID, are connected to any of the pins no. 1 to 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD-signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level. An extra avalanche diode (separate die) clamps the supply line voltage (V_{BUS} at pin 6) above the 12 V working range to ground (pin 7).

Due to the "two die construction" the V_{BUS} line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.





Remark:

The input pins no. 1, 2 and 3 are symmetrical. Each of the data signals D-, D+ and ID can be connected to pin 1, 2 or 3.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

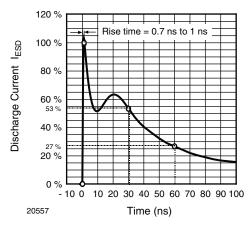


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

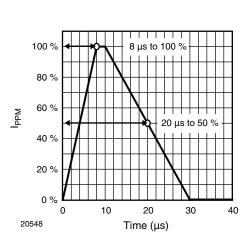


Fig. 2 - 8/20 µs Peak Pulse Current Wave Formacc. IEC 61000-4-5

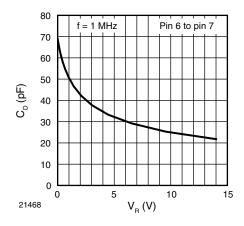


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

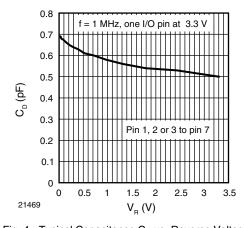


Fig. 4 - Typical Capacitance C_{D} vs. Reverse Voltage V_{R}

Vishay Semiconductors USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 12 \text{ V}$



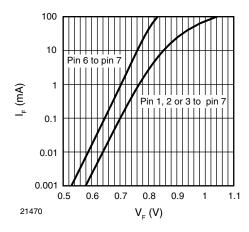


Fig. 5 - Typical Forward Current I_F vs. Forward Voltage V_F

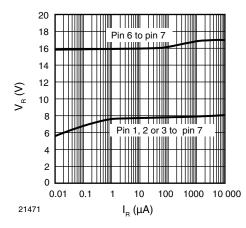


Fig. 6 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

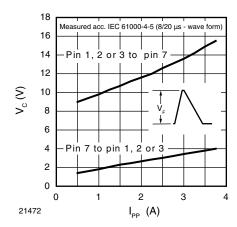


Fig. 7 - Typical Peak Clamping Voltage V_{C} vs. Peak Pulse Current I_{PP}

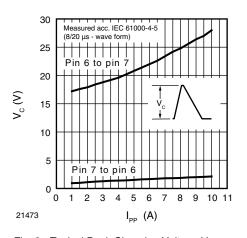
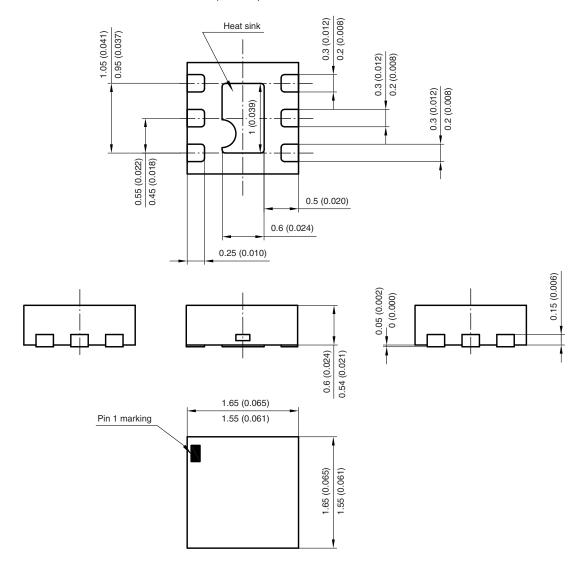


Fig. 8 - Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}

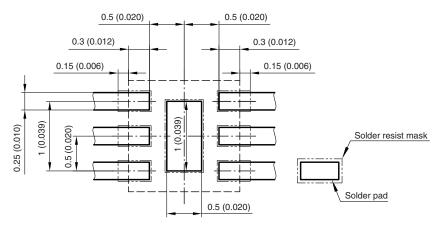


USB-OTG BUS-Port ESD-Protection Vishay Semiconductors for $V_{BUS} = 12 \text{ V}$

PACKAGE DIMENSIONS in millimeters (inches): LLP75-7L



Foot print recommendation:



Document no.:S8-V-3906.02-014 (4) Created - Date: 04. April 2006

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